

# Growth on Imperfect Crystal Faces

Monte-Carlo Method

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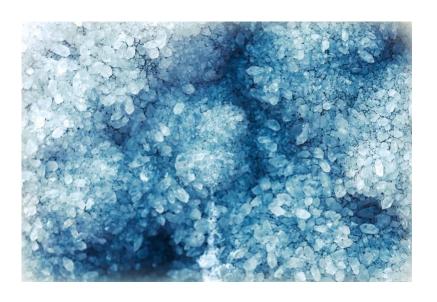
## 1. Motivation

Crystal growth: -Atomic bonding

-Atom mobility

-Surface impurities

Monte-Carlo computer simulations ideal



## 2. Theoretical Background

#### Interface interactions:

- Evaporation: 
$$k_n^- = v \exp(-n\phi/kT)$$

- Impingement: 
$$k^+ = \exp(\Delta \mu/kT) \, k_3^-$$

- Surface migration

## 2. Theoretical Background

#### Interface interactions:

- Evaporation:

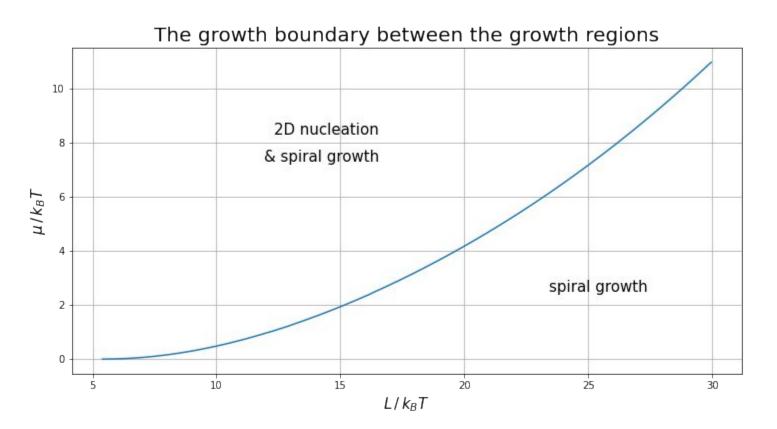
$$\tilde{k}_n^- = \exp(-n\tilde{T})$$

- Impingement:

$$\tilde{k}^+ = \exp(\Delta \tilde{\mu}) \, \tilde{k}_3^-$$

- Surface migration

## 2. Theoretical Background



Divide the surface atoms in subsets based on the number of neighbours of each atom

Select a subset with probability  $p_n$ 

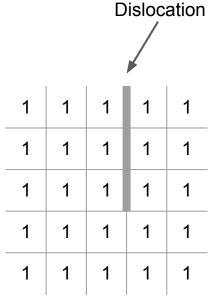
Choose a lattice point from the subset

Choose from of interaction with a probability proportional to their interaction rate

$$p_n = N_n(k_n^- + k^+) / \sum_{i=1}^5 N_i(k_i^- + k^+)$$

Simulate dislocation by introducing scanning matrices

At the boundaries periodic boundary conditions were applied



Surface matrix

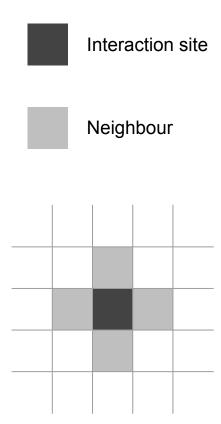
0	0	0	2	0
0	0	0	2	0
0	0	0	2	0
0	0	0	0	0
0	0	0	0	0

Forward scanning matrix

0	0	-2	0	0
0	0	-2	0	0
0	0	-2	0	0
0	0	0	0	0
0	0	0	0	0

Backward scanning matrix

Optimize neighbour scanning by updating the number of neighbours of the lattice sites affected by evaporation, impingement or migration



#### The growth rate:

Every  $N_{
m cycles}$  the crystal surface is stored

$$\Delta h_i = 1/N_{\text{cycles}}(\langle h \rangle_{i+1} - \langle h \rangle_i)$$

$$R/k^+d = 1/n\sum_{i=0}^n \Delta h_i$$

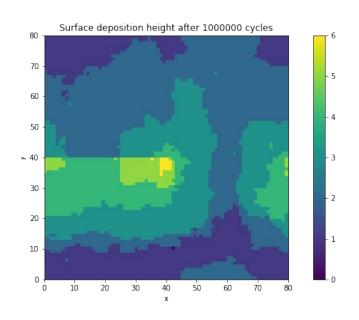
#### **Growth rate error:**

Growth rate is determined from one simulation - thus the data is correlated

The error is determined using the autocorrelation function

$$\chi_A(t) = \frac{1}{\sigma_A^2} \sum_n (A_n - \langle A \rangle)(A_{n+t} - \langle A \rangle)$$
$$\sigma_A = \sqrt{\frac{2\tau}{N} (\langle A^2 \rangle - \langle A \rangle)}$$

## 4. Results

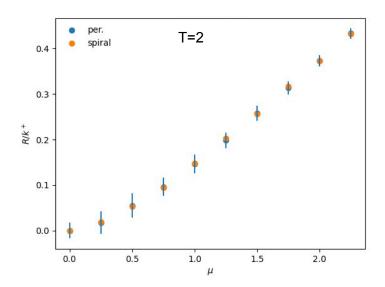


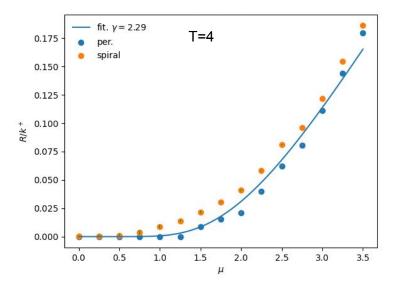
## Spiral growth:

- when does a spiral grow
- what effect does it have

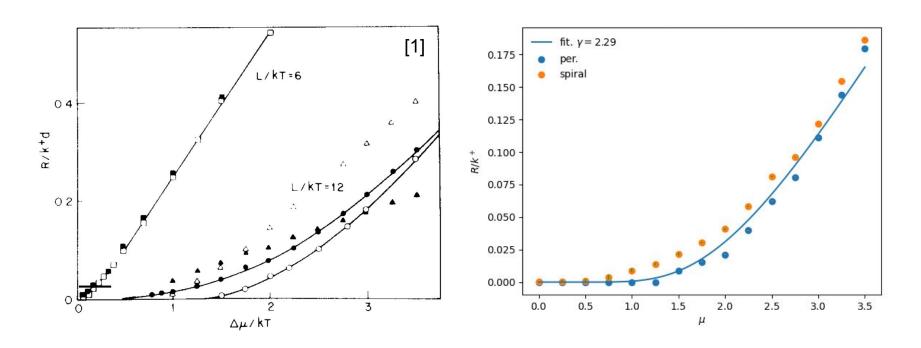
## 4. Results

Only in a small range of T do we see the contribution of spiral growth





## 5. Discussion



## 6. Conclusion & Outlook

- The results in the paper were replicated
- Spiral growth contributes to growth rate in a small window of temperatures.

#### With more time...

 ...we would like to have simulated with surface migrations and analysed these results

### 7. Short video

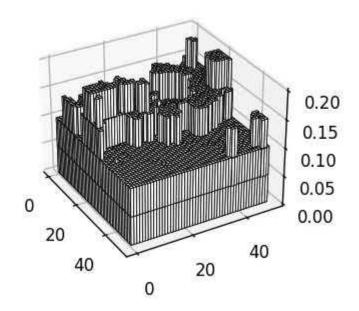
```
dims = [50,50]
T = 6.5
mu = 6
N = 1e5 #attempts

defect introduced at
[0,25]->[15,25]
```

#### Can see:

- Periodic BC
- Plateaus of growth
- Clumps of critical size stay

spirals can't be seen due to small simulation space



#### Source:

[1] G.H. Gilmer, *Growth on imperfect crystal faces: I. Monte-Carlo growth rates*, Journal of Crystal Growth, Volume 36, Issue 1 (1976), Pages 15-28,

# Thank you for your attention

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